

μ PA2464T1Q

R07DS0189EJ0100

Rev.1.00

Dec 06, 2010

MOS FIELD EFFECT TRANSISTOR

Description

The μPA2464T1Q is a switching device, which can be driven directly by a 2.5 V power source.

The μPA2464T1Q features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

Features

- 2.5 V drive available
- Low on-state resistance
 - $R_{DS(on)1} = 26.0 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 4.5 \text{ V}$, $I_D = 3.0 \text{ A}$)
 - $R_{DS(on)2} = 27.0 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 4.0 \text{ V}$, $I_D = 3.0 \text{ A}$)
 - $R_{DS(on)3} = 30.0 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 3.1 \text{ V}$, $I_D = 3.0 \text{ A}$)
 - $R_{DS(on)4} = 38.0 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 2.5 \text{ V}$, $I_D = 3.0 \text{ A}$)
- Built-in G-S protection diode against ESD

Ordering Information

Part No.	LEAD PLATING	PACKING	Package
μ PA2464T1Q-E1-AX *1	Ni/Pd/Au	8 mm embossed taping 3000 p/reel	8-pin HUSON (2720)

Note: *1. Pb-free (This product does not contain Pb in the external electrode and other parts.)

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

Item	Symbol	N-CHANNEL	Unit
Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	30	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	±12	V
Drain Current (DC) *1	$I_{D(DC)}$	±6	A
Drain Current (pulse) *2	$I_{D(pulse)}$	±45	A
Total Power Dissipation (2 unit) *1	P_{T1}	1.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

Notes: *1. Mounted on a glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mm

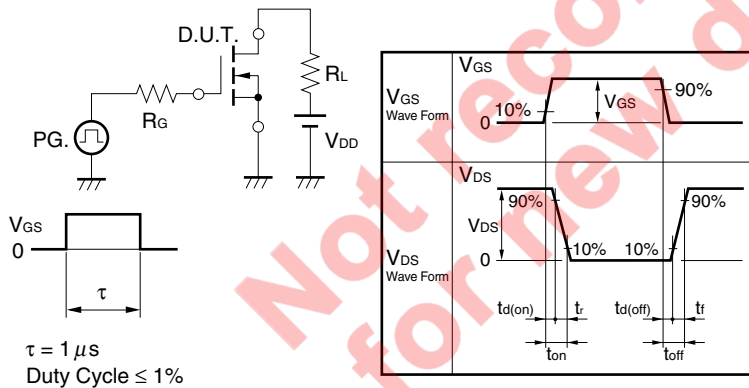
*2. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

Electrical Characteristics (T_A = 25°C)

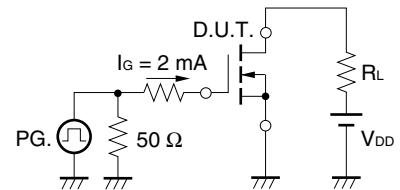
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I _{DSS}			1	μA	V _{DS} = 30 V, V _{GS} = 0 V
Gate Leakage Current	I _{GSS}			±10	μA	V _{GS} = ±12 V, V _{DS} = 0 V
Gate to Source Cut-off Voltage	V _{GS(off)}	0.5	1	1.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance *1	y _{fs}	2.5			S	V _{DS} = 10 V, I _D = 3.0 A
Drain to Source On-state Resistance *1	R _{DS(on)1}	15	20	26	mΩ	V _{GS} = 4.5 V, I _D = 3.0 A
	R _{DS(on)2}	16	20.5	27	mΩ	V _{GS} = 4.0 V, I _D = 3.0 A
	R _{DS(on)3}	17	22	30	mΩ	V _{GS} = 3.1 V, I _D = 3.0 A
	R _{DS(on)4}	19	26	38	mΩ	V _{GS} = 2.5 V, I _D = 3.0 A
Input Capacitance	C _{iss}		700		pF	V _{DS} = 10 V,
Output Capacitance	C _{oss}		77		pF	V _{GS} = 0 V,
Reverse Transfer Capacitance	C _{rss}		48		pF	f = 1 MHz
Turn-on Delay Time	t _{d(on)}		3		μs	V _{DD} = 15 V, I _D = 3.0 A, V _{GS} = 4 V, R _G = 6 Ω
Rise Time	t _r		5		μs	
Turn-off Delay Time	t _{d(off)}		14		μs	
Fall Time	t _f		9		μs	
Total Gate Charge	Q _G		7		nC	V _{DD} = 24 V,
Gate to Source Charge	Q _{GS}		1.3		nC	V _{GS} = 4 V,
Gate to Drain Charge	Q _{GD}		2.5		nC	I _D = 6.0 A
Body Diode Forward Voltage *1	V _{F(S-D)}		0.83		V	I _F = 6.0 A, V _{GS} = 0 V

Note: *1. Pulsed

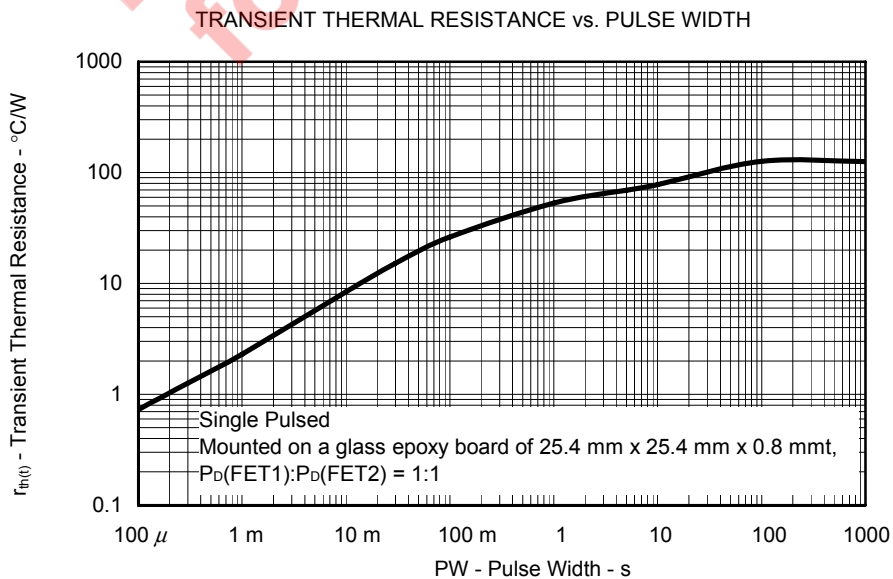
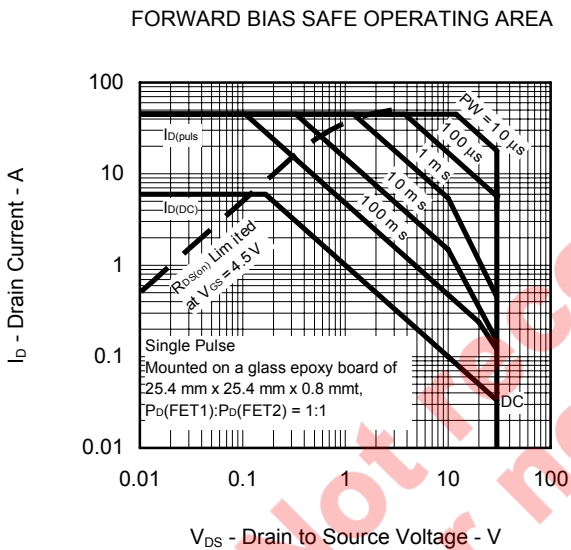
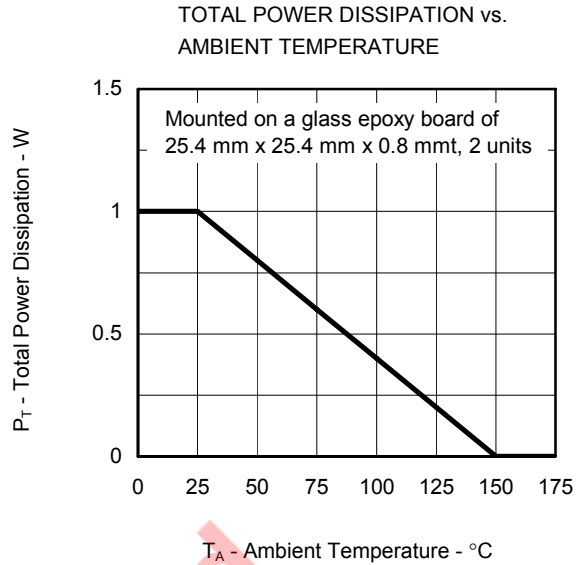
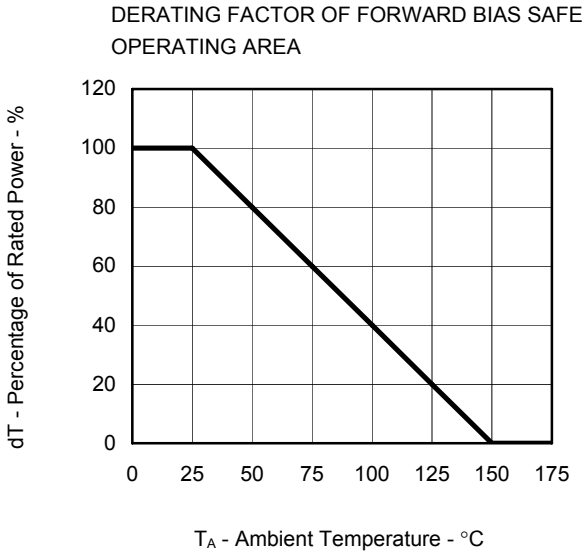
TEST CIRCUIT 1 SWITCHING TIME



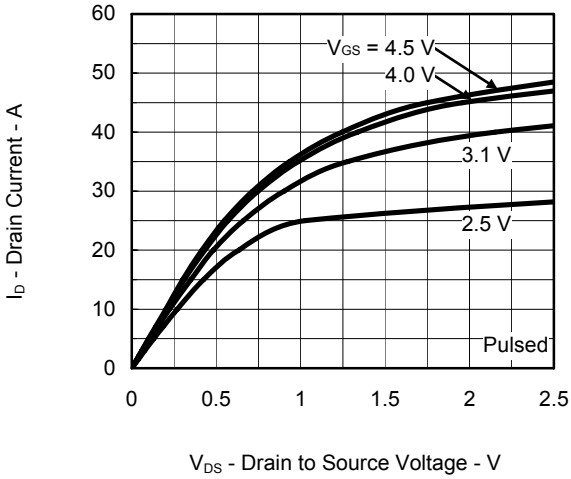
TEST CIRCUIT 2 GATE CHARGE



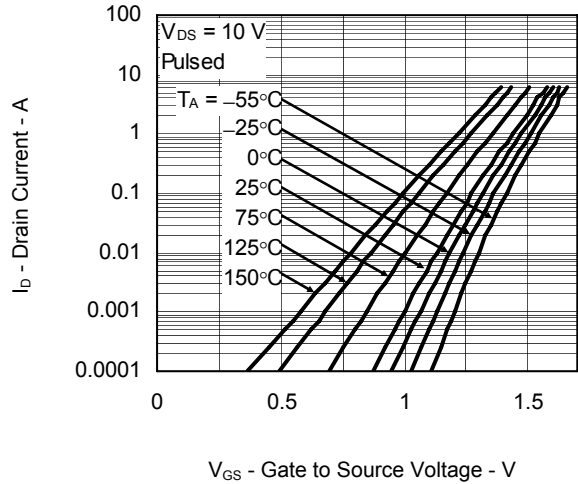
Typical Characteristics (T_A = 25°C)



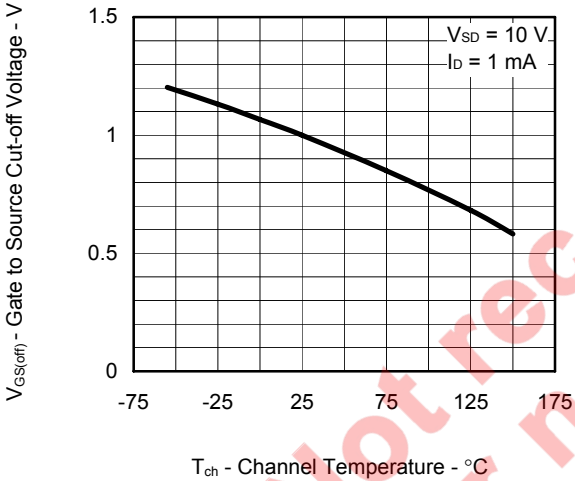
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



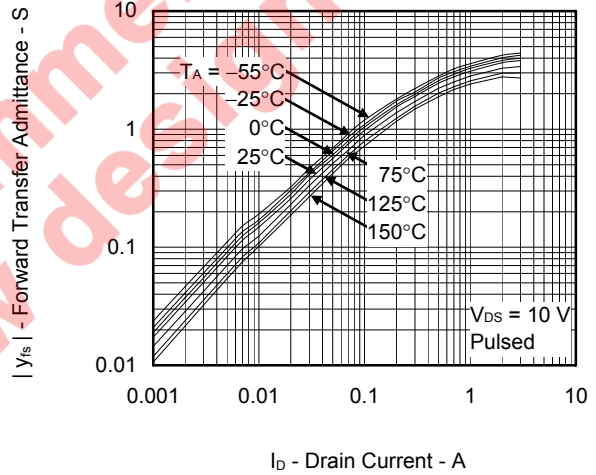
FORWARD TRANSFER CHARACTERISTICS



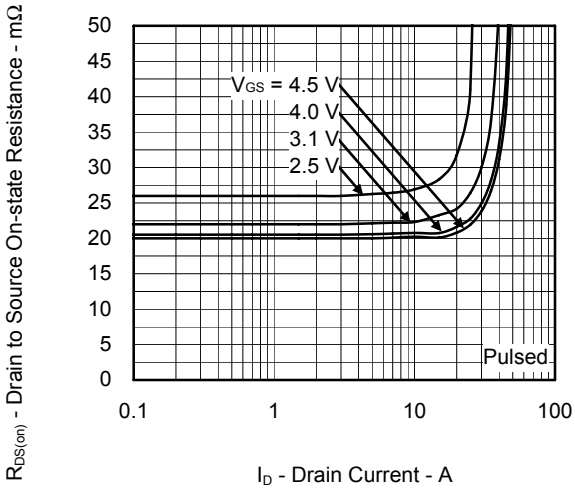
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



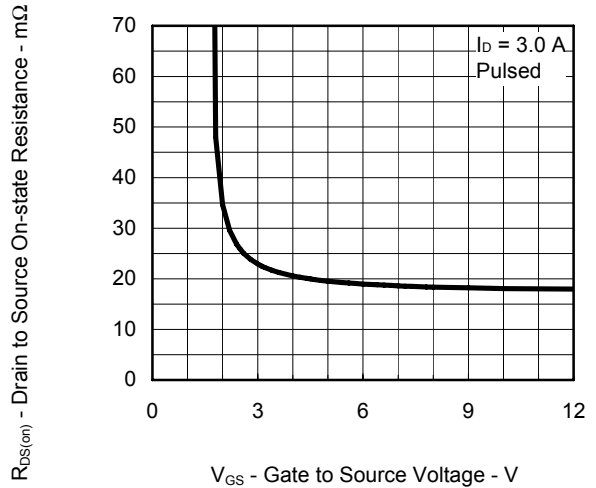
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



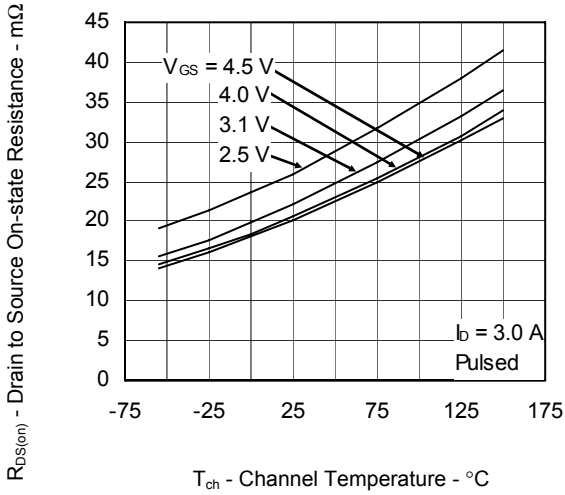
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



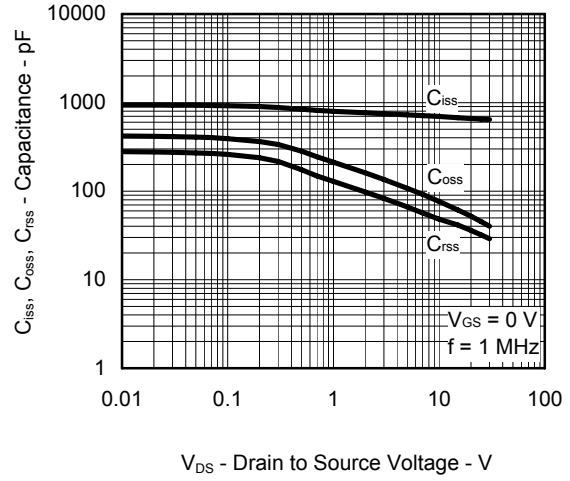
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



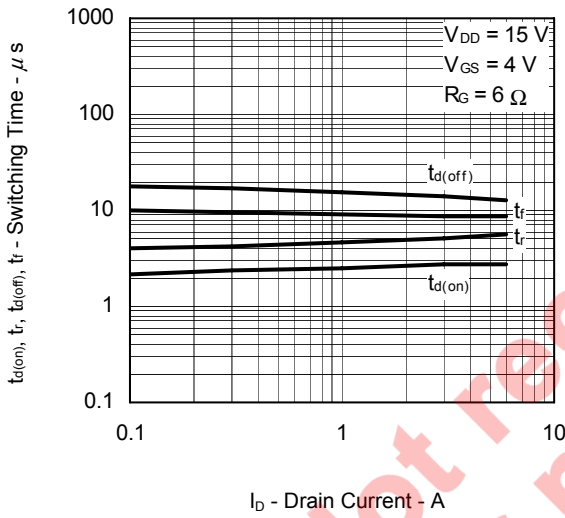
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



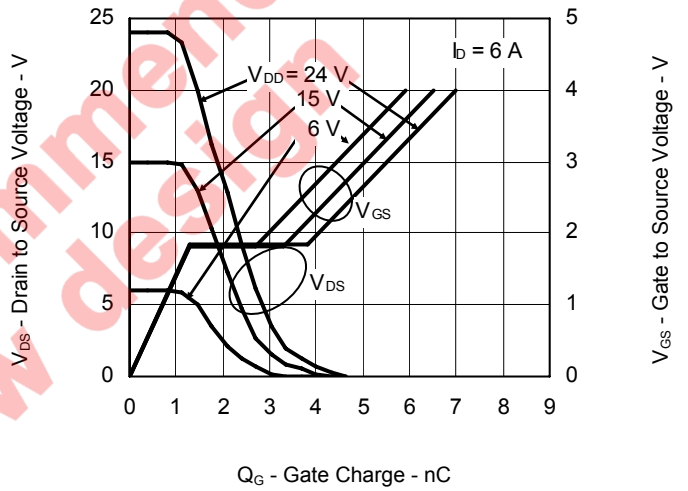
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



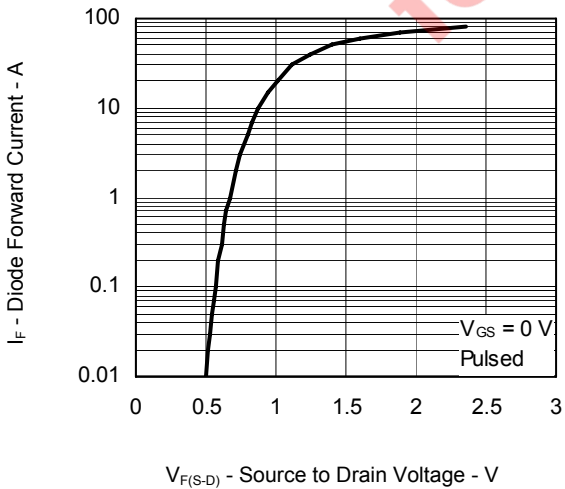
SWITCHING CHARACTERISTICS



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

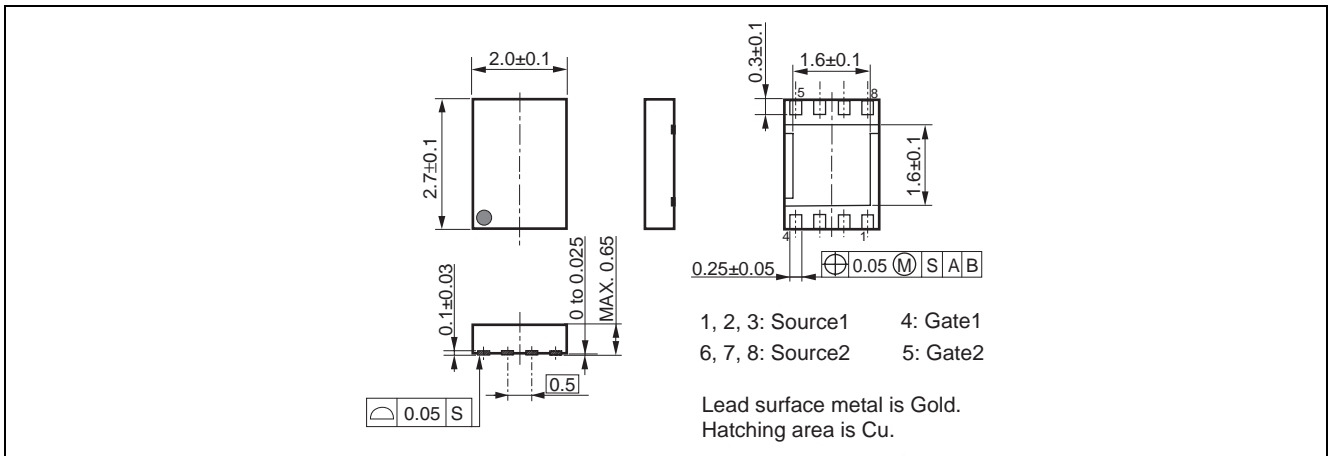


SOURCE TO DRAIN DIODE FORWARD VOLTAGE

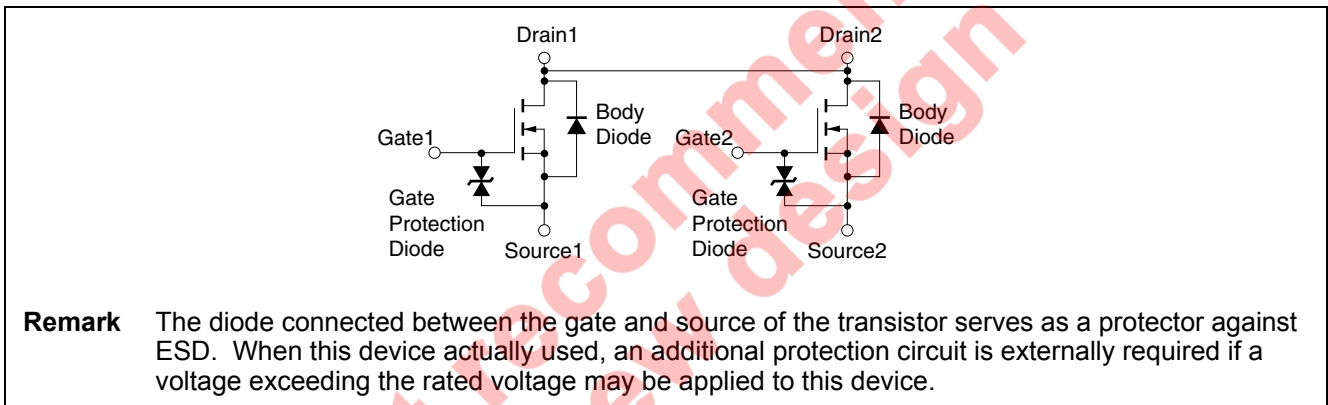


Package Drawings (Unit: mm)

8-pin HUSON (2720)



Equivalent Circuit



Revision History	μPA2464T1Q Data Sheet
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Rev.	Date	Description	
		Page	Summary
1.00	Dec 06, 2010	–	First Edition Issued

**Not recommend
for new design**

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